Code No.: AP202BS

H.T.No. R20

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CMR ENGINEERING COLLEGE: : HYDERABAD **UGC AUTONOMOUS**

I-B.TECH-II-Semester End Examinations (Supply) - January- 2022 APPLIED PHYSICS

(Common to CSM, ECE, ME)

[Time: 3 Hours]

[Max. Marks: 70]

Note: This question paper contains two parts A and B. Part A is compulsory which carries 20 marks. Answer all questions in Part A. Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions. (20 Marks) PART-A State any two drawbacks of classical free electron theory.

[2M] The wavelength associated with a moving particle is given as $\lambda = h/p$, where h is Planck's constant and p [2M] is the momentum of the particle. Calculate the wavelength of an electron moving with one tenth speed of How a pure semiconductor material of tetra valance is modified as p-type semiconductor? [2M] c) [2M] Distinguish direct and indirect band semi conductors. What is pyro-electricity and give an example of pyro-electric material? Write down the expression for atomic Bohr Magneton, indicating the terms in it. If actual lasing action takes place in Neon atoms in He-Ne laser, what is the necessity to add Helium gas Explain the principle of light propagation in an optical fiber. h) The size of virus is in the range 0.02-0.25 micron, Express it in nano dimensions. Expand the terms XRD, SEM and TEM usually used in characterization of nano materials. (50 Marks) PART-B

[2M] [2M][2M] [2M] [2M] [2M] [4M] a) Derive time independent Schrodinger wave equation. b) Obtain the energy and wave functions for a particle in infinite one dimensional potential. [6M] [5M] 3. a) Describe qualitatively the behavior of electron in a periodically varying potential in a real crystal. b) What is Uncertainty principle in terms of momentum and position and as an application of it [5M] show why electrons are not stable particles in an atomic nucleus? [4M] a) Describe the phenomenon of the Hall effect, explain the applications of it. [6M] b) What is intrinsic carrier concentration in a semiconductor and obtain an expression for it. [5M] a) State the principle of solar cell and detail its working. b) To prepare an LED that emits red light of wavelength 690 nm, what should be the energy [3M] gap of the semiconductor material used? [2M] c) What is solar cell form factor and mention its physical significance? [6M] a) Discuss the Hysteresis loop in ferro magnetic material based on domain theory. [4M] b) Compare dia-, para- and ferro-magnetic materials. [7M]

a) Derive an expression for local field in a symmetrical dielectric crystal. [3M] b) Write short notes on pizeo-electric materials.

8.	a) Describe the principle, construction and working of He-Ne laser.	[6M]
	b) Brief the terms: (i) stimulated emission, (ii) meta-stable state, (iii) population inversion and (iv)	[4M]
	pumping mechanism.	
	OR	
9.	a) Discuss various attenuation mechanisms in optical fibers.	[5M]
	b) Discuss step index and graded index types of optical fibers.	[5M]
10.	a) Describe any one of the top-down approaches of preparation of nano materials.	[6M]
	b) What is surface-to-volume ratio and how it plays important role in determining the properties of nano materials?	[4M]
	OR	
11.	a) Explain in detail the Sol-Gel process of nano material preparation.	[6M]
	b) Mention any four important applications of nano materials.	[4M]
